PECLERS®

KBPC8005 THRU KBPC810

SINGLE-PHASE SILICON BRIDGE RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 8.0 AMPERE

FEATURES

- · Reliable low cost construction
- · Ideal for printed circuit board
- · Low forward voltage drop
- · Low reverse leakage current
- · High surge current capability

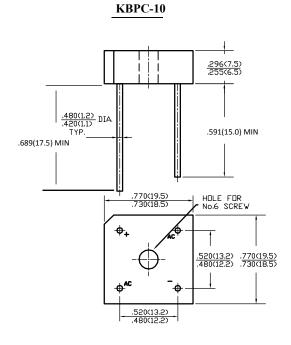
MECHANICAL DATA

Case: Molded plastic, KBPC-8

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202,

method 208 guaranteed Mounting position: Any Weight: 0.24ounce, 6.9gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	KBPC8005	KBPC801	KBPC802	KBPC804	KBPC806	KBPC808	KBPC810	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward	ī	8.0							Amp
Rectified Current at T _C =50℃	I _(AV)								
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I_{FSM}	I _{FSM} 125							Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage Drop per Element	V_{F}	1.1							Volts
at 4.0 A DC and 25 °C	▼ F								
Maximum Reverse Current at T _A =25℃	I_R	10.0							uAmp
at Rated DC Blocking Voltage T _A =100℃	I _R	500							
Typical Junction Capacitance (Note 1)	C_{J}	100							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	20							°C/W
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	9.4							℃/W
Operating and Storage Temperature Range	T _J , Tstg	-55 to +150							ဗ

NOTES:

- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Unit mounted on 8.6 x 8.6 x 0.24" thick (22 x 22 x 0.6cm) Al. Plate
- 3- Unit mounted on P.C.B. at 0.375" (9.5mm) lead length with 0.5×0.5 " (12 x 12mm) copper pads



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RATINGS AND CHARACTERISTIC CURVES

FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

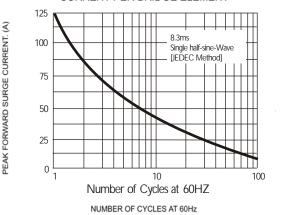


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

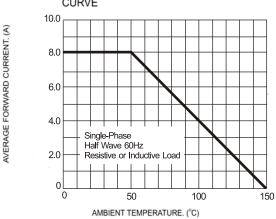
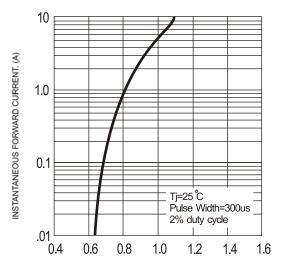


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT



INSTANTANEOUS FORWARD VOLTAGE. (V)

FIG.4- TYPICAL REVERSE CHARACTERISTICS

